

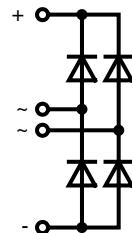
# Single Phase Rectifier Bridge

Standard and Avalanche Types

$I_{dAV} = 18 \text{ A}$   
 $V_{RRM} = 800-1600 \text{ V}$

$V_{RSM}$ V	$V_{BRmin}$ <sup>①</sup> V	$V_{RRM}$ V	Standard Types	Avalanche Types
900		800	VBO 13-08N02	
1300	1230	1200	VBO 13-12N02	VBO 13-12AO2
1700	1630	1600	VBO 13-16N02	VBO 13-16AO2

① For Avalanche Types only



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Symbol	Conditions	Maximum Ratings		
$I_{dAV}$ ②	$T_C = 85^\circ\text{C}$ , module	18	A	
$I_{dAVM}$	module	30	A	
$P_{RSM}$	$T_{VJ} = T_{VJM}$	2.5	kW	
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $V_R = 0$	220	A	
	$t = 10 \text{ ms}$ (50 Hz) $t = 8.3 \text{ ms}$ (60 Hz)	230	A	
	$T_{VJ} = T_{VJM}$ ; $V_R = 0$	180	A	
	$t = 10 \text{ ms}$ (50 Hz) $t = 8.3 \text{ ms}$ (60 Hz)	190	A	
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ ; $V_R = 0$	240	$\text{A}^2\text{s}$	
	$t = 10 \text{ ms}$ (50 Hz) $t = 8.3 \text{ ms}$ (60 Hz)	220	$\text{A}^2\text{s}$	
	$T_{VJ} = T_{VJM}$ ; $V_R = 0$	160	$\text{A}^2\text{s}$	
	$t = 10 \text{ ms}$ (50 Hz) $t = 8.3 \text{ ms}$ (60 Hz)	150	$\text{A}^2\text{s}$	
$T_{VJ}$		-40...+150	$^\circ\text{C}$	
$T_{VJM}$		150	$^\circ\text{C}$	
$T_{stg}$		-40...+125	$^\circ\text{C}$	
$V_{ISOL}$	50/60 Hz, RMS	3000	V $\sim$	
	$I_{ISOL} \leq 1 \text{ mA}$	3600	V $\sim$	
$M_d$	Mounting torque (M5) (10-32 UNF)	1.5-2 13-18	Nm lb.in.	
<b>Weight</b>	Typ.	15	g	

Symbol	Conditions	Characteristic Values		
$I_R$	$V_R = V_{RRM}$	0.3	mA	
	$T_{VJ} = 25^\circ\text{C}$	5.0	mA	
	$T_{VJ} = T_{VJM}$			
$V_F$	$I_F = 55 \text{ A}$	1.8	V	
$V_{TO}$	For power-loss calculations only	0.85	V	
$r_t$		17	$\text{m}\Omega$	
$R_{thJC}$	per diode; 120° el. per module	5.60 1.40	K/W	
$R_{thJH}$	per diode; 120° el. per module	6.00 1.50	K/W	
$d_s$	Creeping distance on surface	13	mm	
$d_A$	Creepage distance in air ③	9.5	mm	
$a$	Max. allowable acceleration	50	$\text{m}/\text{s}^2$	

Data according to IEC 60747 and refer to a single diode unless otherwise stated.

② for resistive load at bridge output

③ with isolated fast-on tabs.

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## Features

- Avalanche rated parts available
- Package with DCB ceramic base plate
- Isolation voltage 3600 V $\sim$
- Planar passivated chips
- Low forward voltage drop
- 1/4" fast-on terminals
- UL registered E 72873

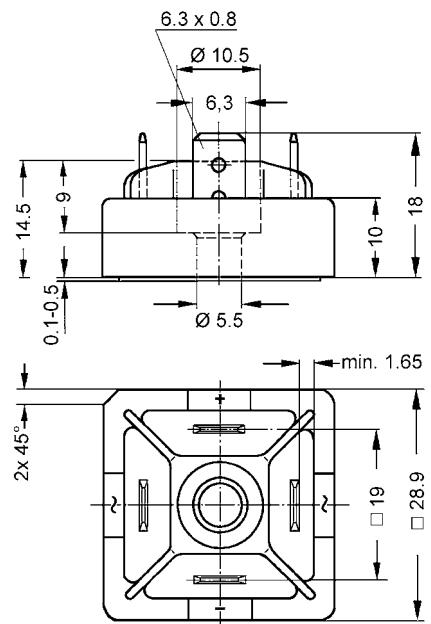
## Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

## Advantages

- Easy to mount with one screw
- Space and weight savings
- Improved temperature & power cycling

## Dimensions in mm (1 mm = 0.0394")



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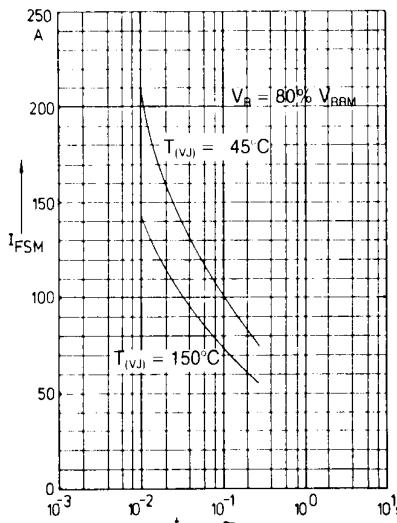


Fig. 1 Surge overload current per diode  
 $I_{FSM}$ : Crest value,  $t$ : duration

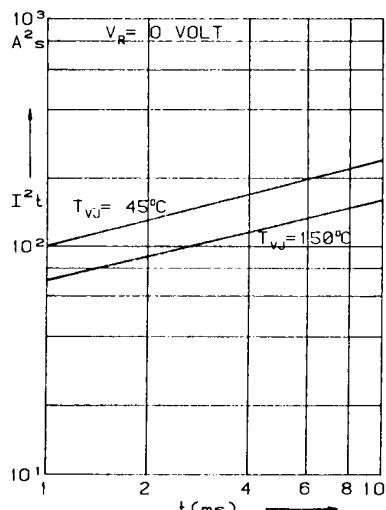


Fig. 2  $I^2t$  versus time (1-10 ms)  
per diode

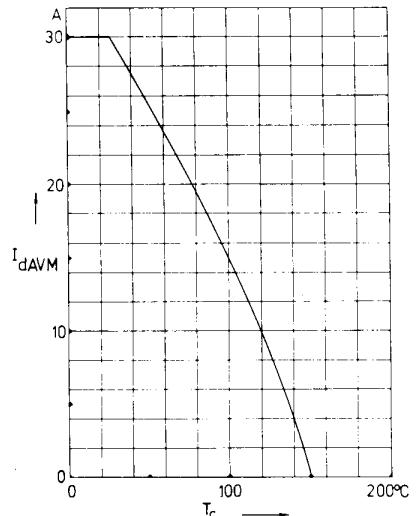


Fig. 3 Max. forward current at case temperature

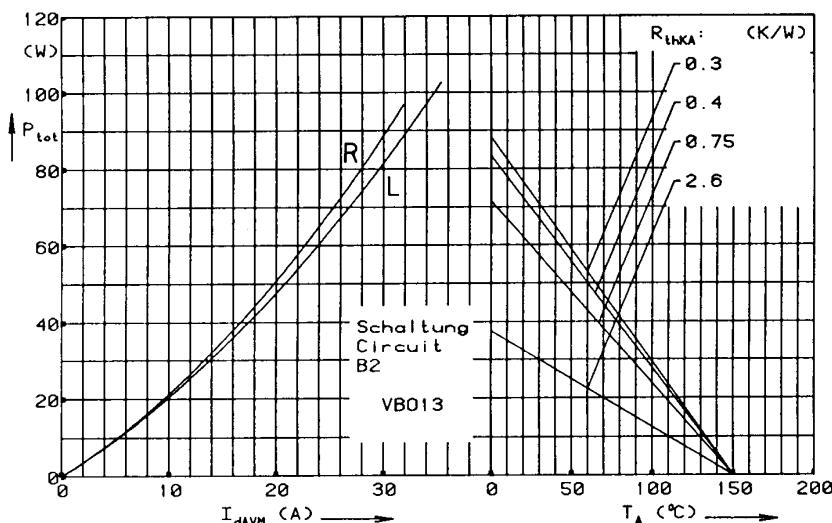


Fig. 4 Power dissipation versus direct output current and ambient temperature

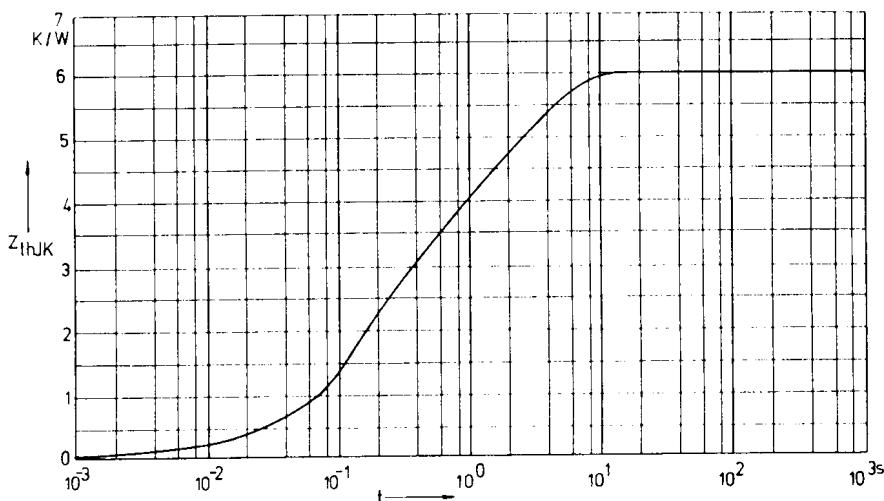


Fig. 5 Transient thermal impedance junction to heatsink per diode

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Constants for  $Z_{thJK}$  calculation:

$i$	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.059	0.00217
2	2.714	0.159
3	3.227	2.34